

Mini DomiLED

With the intense colors that seem to glow with energy and its significant brightness, Mini DomiLED white LED is a highly reliable design device. Its dynamic nature makes it perfect choice for lighthing applications, office and home applications and standard industrial applications.



Features:

- > High brightness surface mount LED.
- > Based on InGaN technology.
- > 120° viewing angle.
- > Small package outline (LxWxH) of 2.0 x 1.4 x 1.3mm.
- > Qualified according to JEDEC moisture sensitivity Level 2.
- > Compatible to both IR reflow soldering.
- > Environmental friendly; RoHS compliance.
- > Compliance to automotive standard; AEC-Q102.
- > Passed Corrosion Resistant Test.



Applications:

- > Automotive: interior applications, eg: switches, telematics, climate control system, dashboard, etc.
- > Communication: indicator and backlight in mobilephone.
- > Display: full color display video notice board.
- > Industry: white goods (eg: Oven, microwave, etc.).



Optical Characteristics at Tj=25°C

Part Number	Viewing Angle°	Luminous Intensity @ IF = 10mA IV (mcd) <i>Appx. 1.1</i>		
		Min.	Typ.	Max.
DNZB-DJG-R2S-1-I1	120	140.0	224.0	285.0

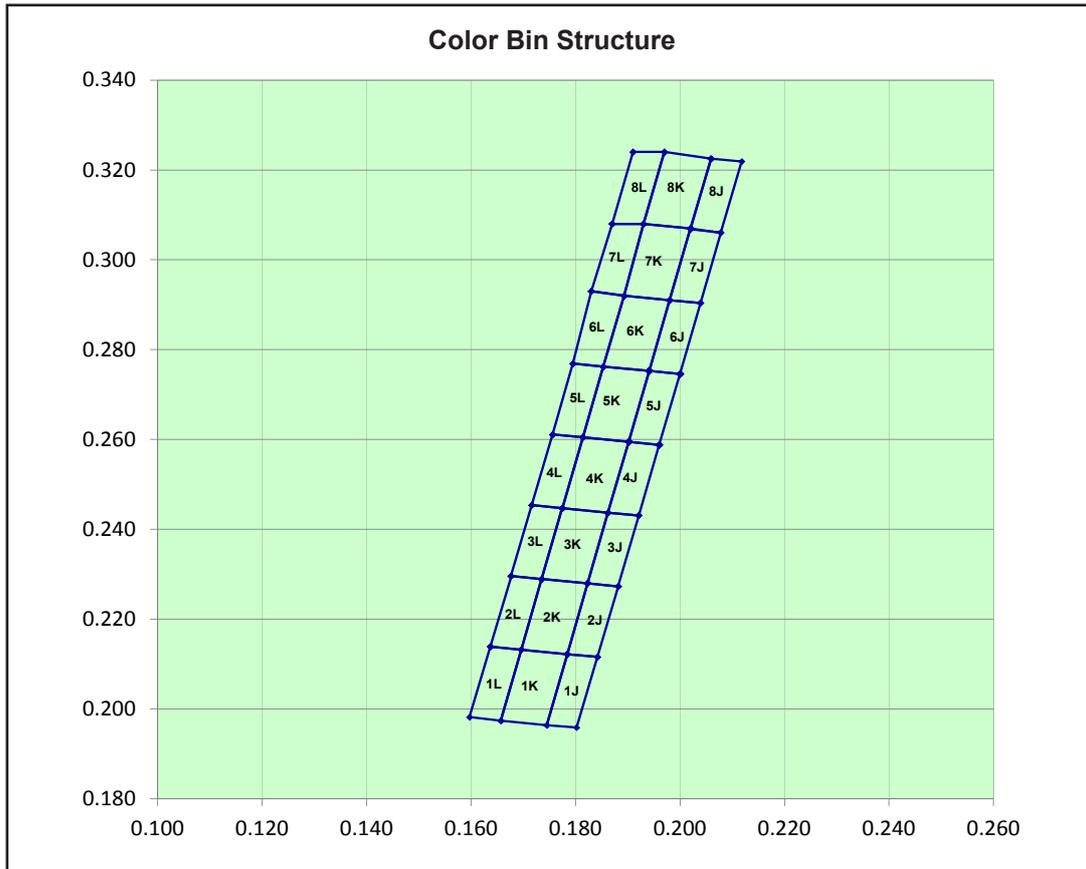
Electrical Characteristics at Tj=25°C

Part Number	Vf @ If = 10 mA <i>Appx. 3.1</i>			Vr @ Ir = 10 µA
	Min. (V)	Typ. (V)	Max. (V)	Min. (V)
DNZB-DJG	2.70	3.00	3.50	5.0

Absolute Maximum Ratings

	Maximum Value	Unit
DC forward current	20	mA
Peak pulse current; (Ts = 55°C, tp ≤ 100µs, Duty cycle = 0.03)	100	mA
Reverse voltage	5	V
ESD threshold (HBM)	2000	V
LED junction temperature	110	°C
Operating temperature	-40 ... +105	°C
Storage temperature	-40 ... +105	°C
Power dissipation (at room temperature)	70	mW
Thermal resistance		
- Junction / ambient, R _{th JA}	530	K/W
- Junction / solder point, R _{th JS}	280	K/W

DNZB-DJG Color Grouping *Appx. 2.1*



Bin		1	2	3	4
1J	Cx	0.1784	0.1842	0.1802	0.1745
	Cy	0.2122	0.2116	0.1959	0.1964
1K	Cx	0.1696	0.1784	0.1745	0.1657
	Cy	0.2132	0.2122	0.1964	0.1974
1L	Cx	0.1637	0.1696	0.1657	0.1597
	Cy	0.2139	0.2132	0.1974	0.1982
2J	Cx	0.1784	0.1842	0.1882	0.1823
	Cy	0.2122	0.2116	0.2273	0.2280
2K	Cx	0.1696	0.1784	0.1823	0.1735
	Cy	0.2132	0.2122	0.2280	0.2290
2L	Cx	0.1637	0.1696	0.1735	0.1677
	Cy	0.2139	0.2132	0.2296	0.2296
3J	Cx	0.1862	0.1823	0.1881	0.1921
	Cy	0.2437	0.2280	0.2273	0.2431
3K	Cx	0.1774	0.1735	0.1823	0.1862
	Cy	0.2447	0.2289	0.2280	0.2437
3L	Cx	0.1716	0.1676	0.1735	0.1774
	Cy	0.2454	0.2296	0.2289	0.2447
4J	Cx	0.1902	0.1862	0.1921	0.1960
	Cy	0.2595	0.2437	0.2431	0.2588
4K	Cx	0.1814	0.1775	0.1862	0.1902
	Cy	0.2605	0.2447	0.2437	0.2595
4L	Cx	0.1756	0.1716	0.1775	0.1814
	Cy	0.2611	0.2454	0.2447	0.2605

Bin		1	2	3	4
5J	Cx	0.1941	0.1902	0.1960	0.2000
	Cy	0.2753	0.2595	0.2588	0.2746
5K	Cx	0.1853	0.1814	0.1902	0.1941
	Cy	0.2762	0.2605	0.2595	0.2753
5L	Cx	0.1795	0.1756	0.1814	0.1853
	Cy	0.2769	0.2611	0.2605	0.2762
6J	Cx	0.1980	0.1941	0.2000	0.2039
	Cy	0.2910	0.2753	0.2746	0.2904
6K	Cx	0.1893	0.1853	0.1941	0.1980
	Cy	0.2920	0.2762	0.2753	0.2910
6L	Cx	0.1830	0.1795	0.1853	0.1893
	Cy	0.2930	0.2769	0.2762	0.2920
7J	Cx	0.2020	0.1980	0.2039	0.2078
	Cy	0.3070	0.2910	0.2904	0.3060
7K	Cx	0.1930	0.1893	0.1980	0.2020
	Cy	0.3080	0.2920	0.2910	0.3070
7L	Cx	0.1870	0.1830	0.1893	0.1930
	Cy	0.3080	0.2930	0.2920	0.3080
8J	Cx	0.2059	0.2020	0.2078	0.2118
	Cy	0.3225	0.3068	0.3061	0.3219
8K	Cx	0.1970	0.1930	0.2020	0.2060
	Cy	0.3240	0.3080	0.3070	0.3230
8L	Cx	0.1910	0.1870	0.1930	0.1970
	Cy	0.3240	0.3080	0.3080	0.3240

InGaN wavelength is very sensitive to drive current. Operating at lower current is not recommended and may yield unpredictable performance. Current pulsing should be used for dimming purposes.

Luminous Intensity Group at Tj=25°C

Brightness Group	Luminous Intensity <i>Appx. 1.1</i> IV (mcd)
R2	140.0 ... 180.0
S1	180.0 ... 224.0
S2	224.0 ... 285.0

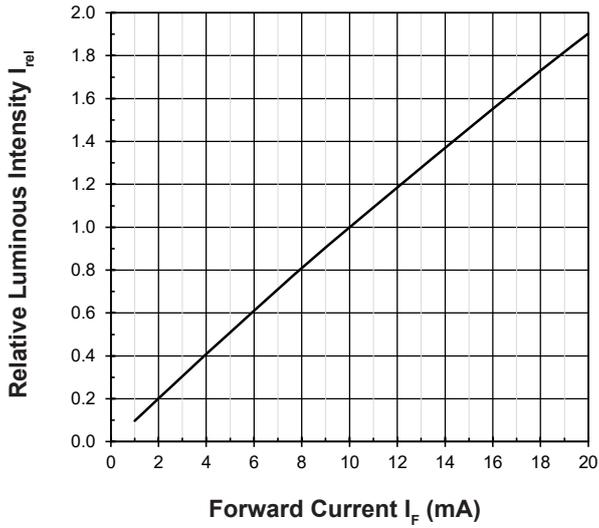
Vf Binning (Optional)

Vf @ If = 10mA	Forward Voltage (V) <i>Appx. 3.1</i>
M6	2.70 ... 3.00
M7	3.00 ... 3.30
M8	3.30 ... 3.60

Please consult sales and marketing for special part number to incorporate Vf binning.

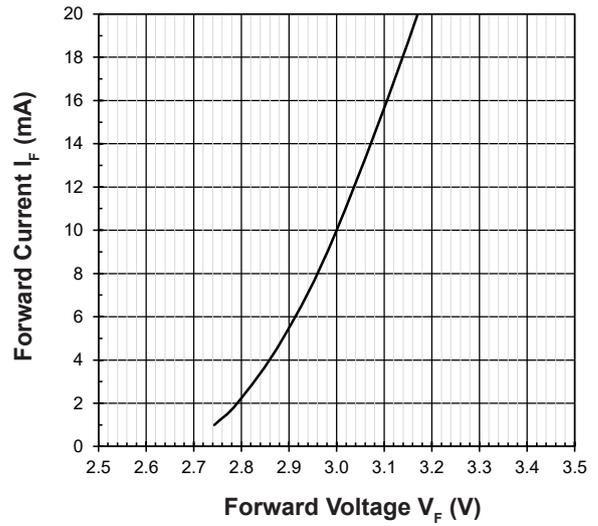
Relative Luminous Intensity Vs Forward Current *Appx. 4.1*

$I_v/I_v(10\text{mA}) = f(I_F); T_j = 25^\circ\text{C}$



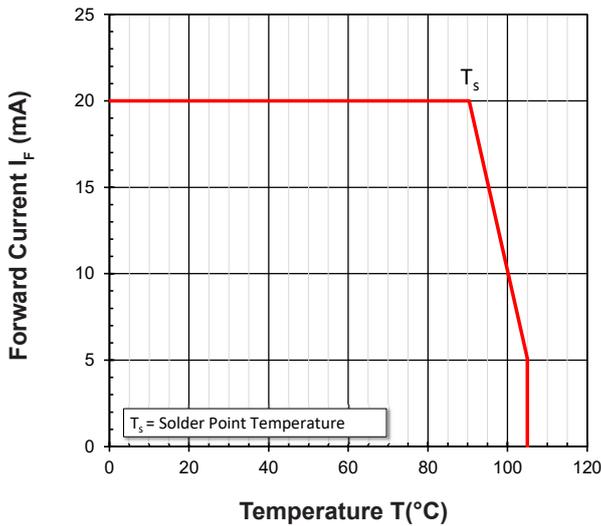
Forward Current Vs Forward Voltage *Appx. 4.1*

$I_F = f(V_F); T_j = 25^\circ\text{C}$



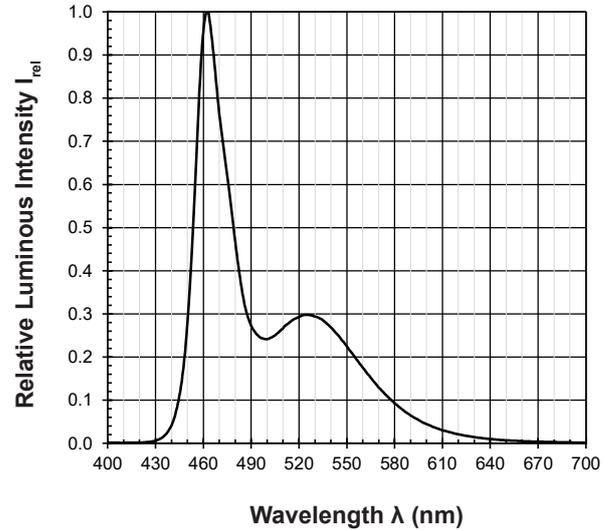
Maximum Current Vs Temperature

$I_F = f(T)$



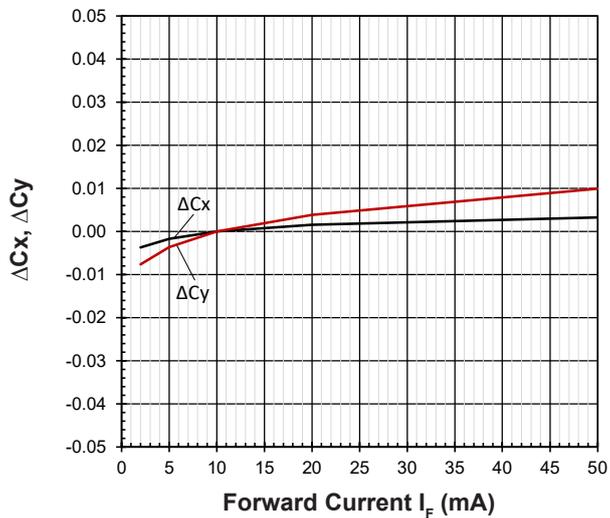
Relative Spectral Emission *Appx. 4.1*

$I_{rel} = f(\lambda); T_j = 25^\circ\text{C}; I_F = 10\text{mA}$



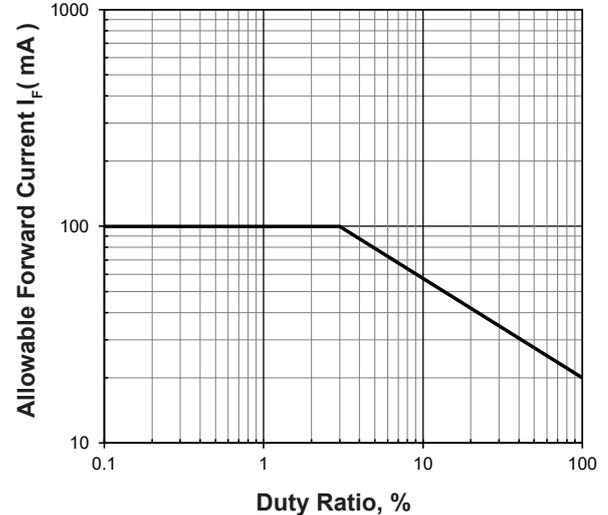
Chromaticity Coordinate Shift Vs Forward Current *Appx. 4.1*

$\Delta Cx, \Delta Cy = f(I_F); T_j = 25^\circ\text{C}$

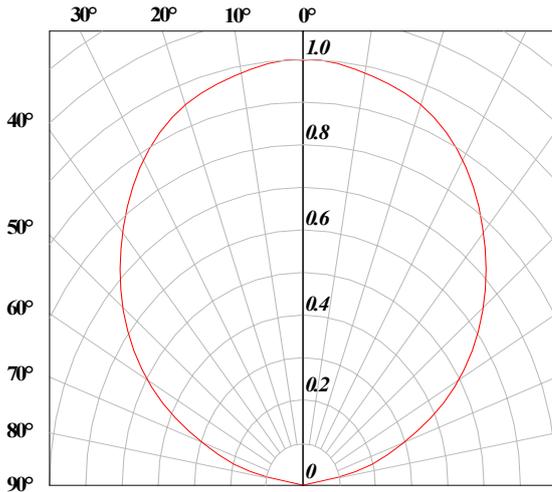


Allowable Forward Current Vs Duty Ratio

$(T_s = 55^\circ\text{C}; t_p \leq 100\mu\text{s})$

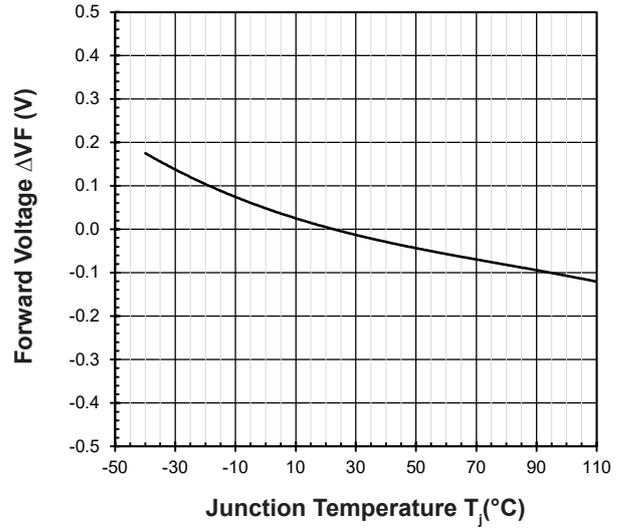


Radiation Pattern *Appx. 4.1*



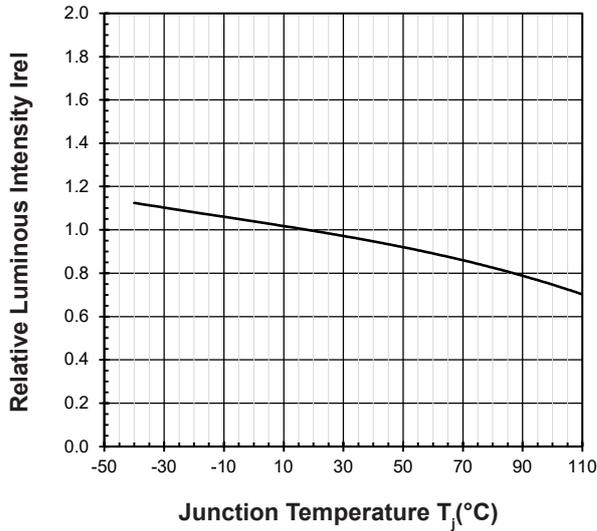
Forward Voltage Vs Junction Temperature *Appx. 4.1*

$\Delta VF = VF - VF(25^\circ C) = f(T_j); I_F = 10mA$



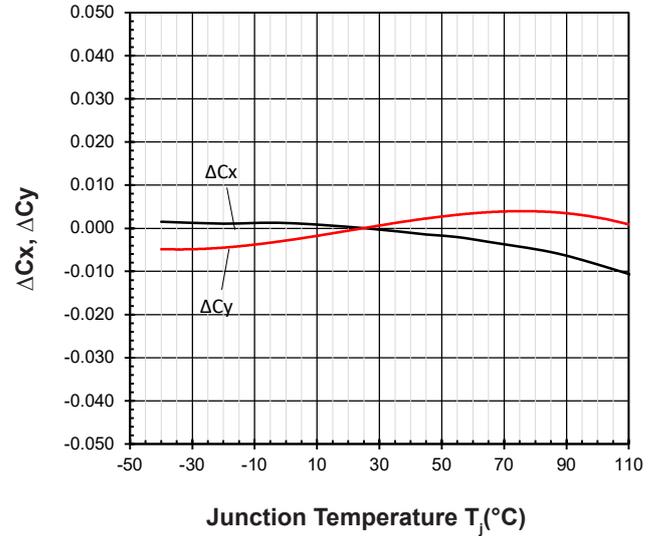
Relative Luminous Intensity Vs Junction Temperature *Appx. 4.1*

$I_V / I_V(25^\circ C) = f(T_j); I_V = 10mA$

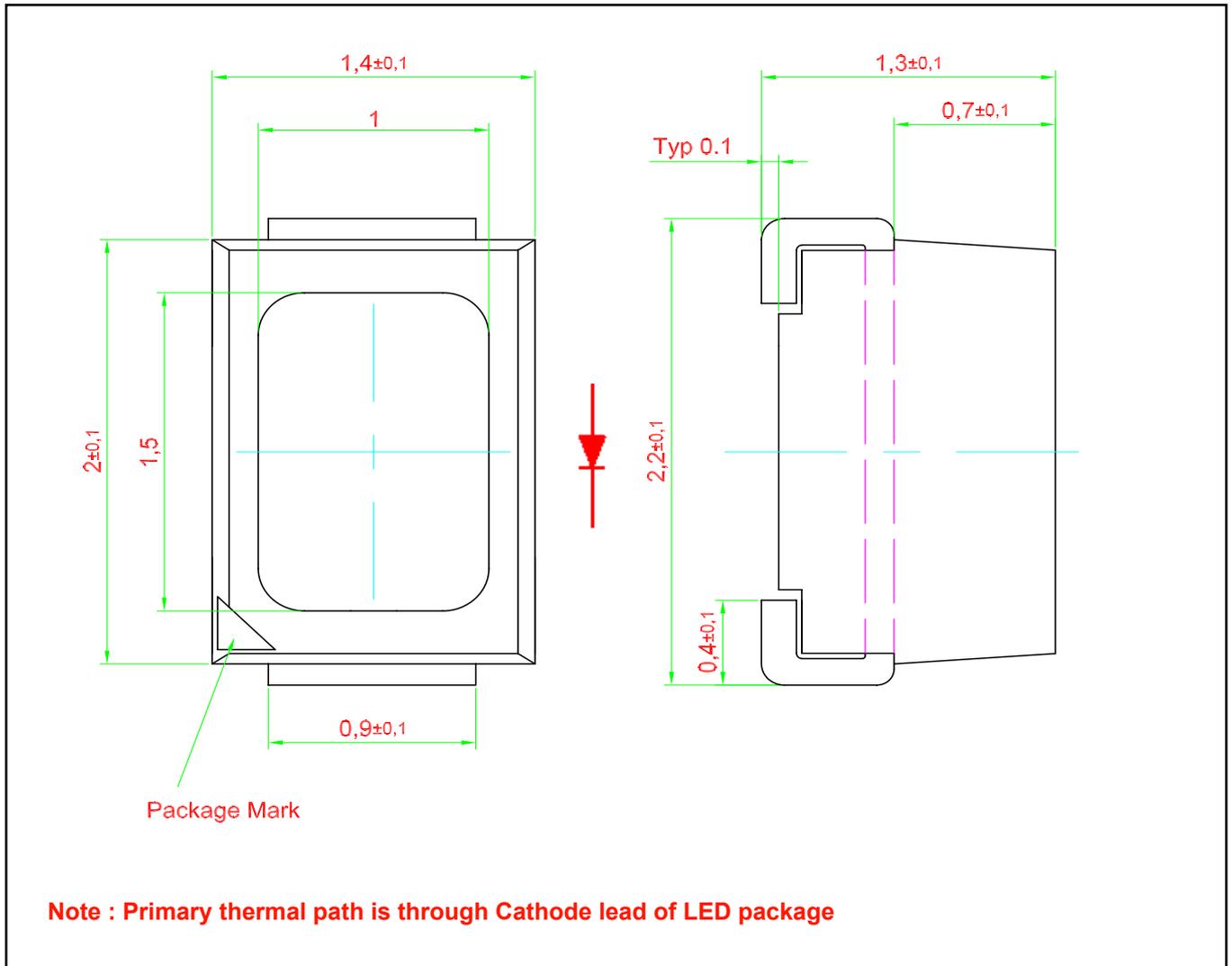


Chromaticity Coordinate Shift Vs Junction Temperature *Appx. 4.1*

$\Delta C_x, \Delta C_y = f(T_j); I_F = 10mA$



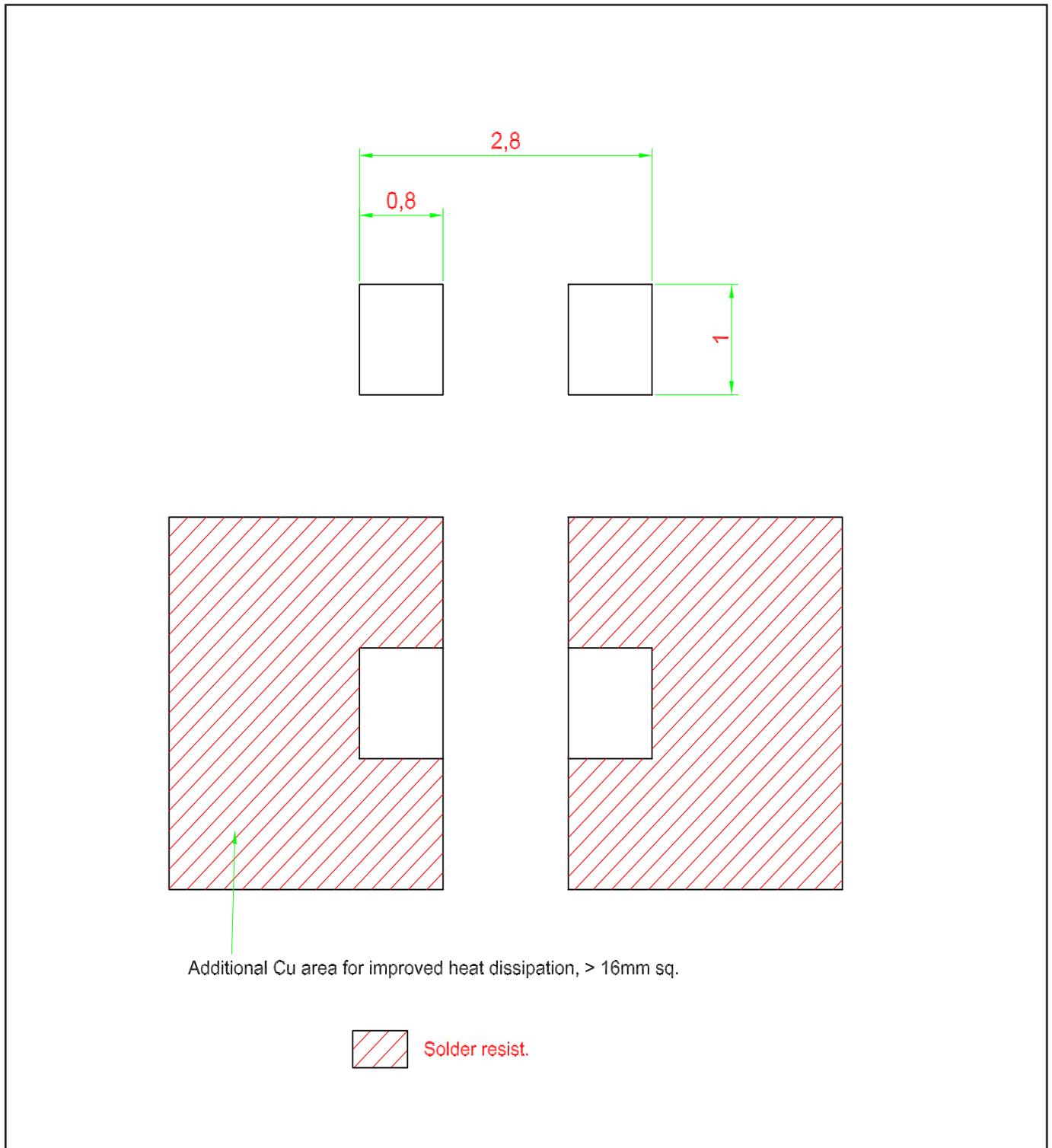
Mini DomiLED • InGaN: DNZB-DJG-I1 Package Outlines *Appx. 5.1*



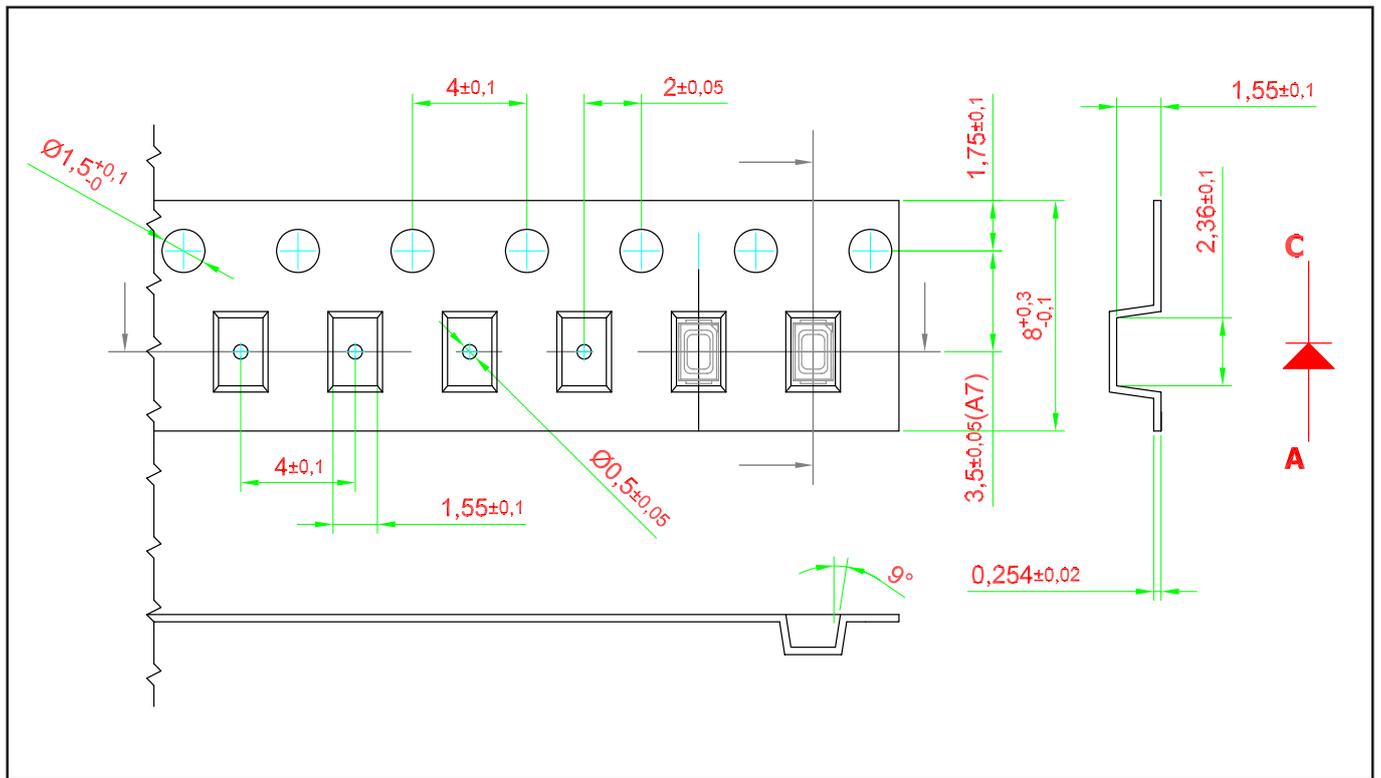
Material

Material	
Lead-frame	Cu Alloy With Ag Plating
Package	High Temperature Resistant Plastic
Encapsulant	Silicone
Soldering Leads	Sn Plating

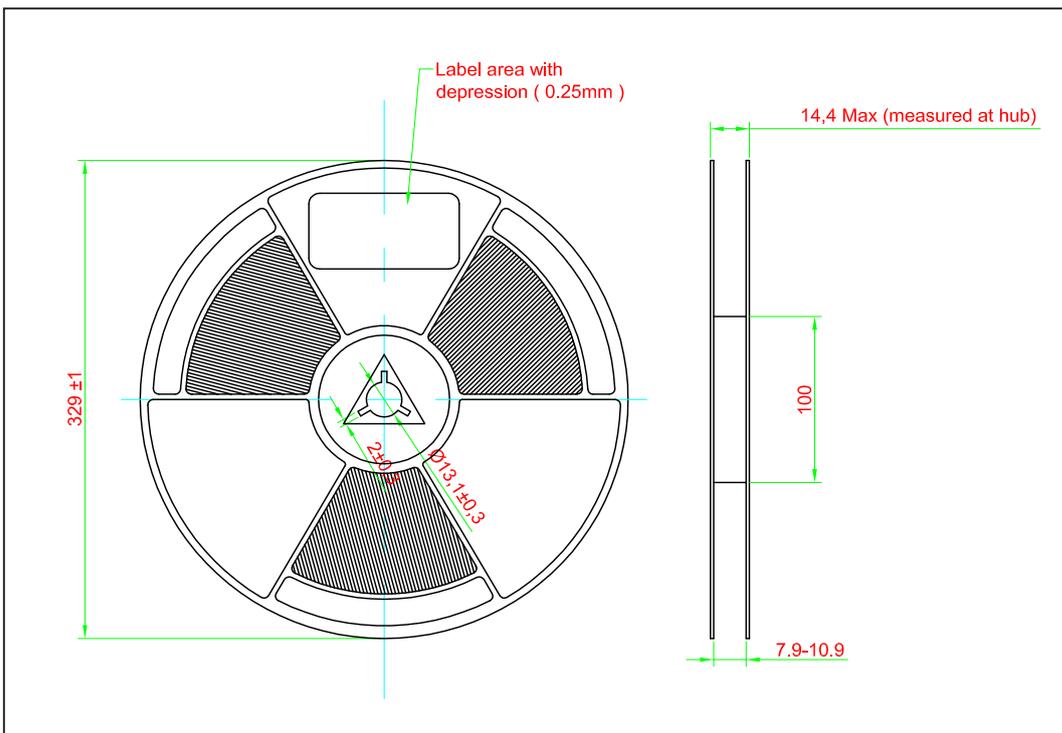
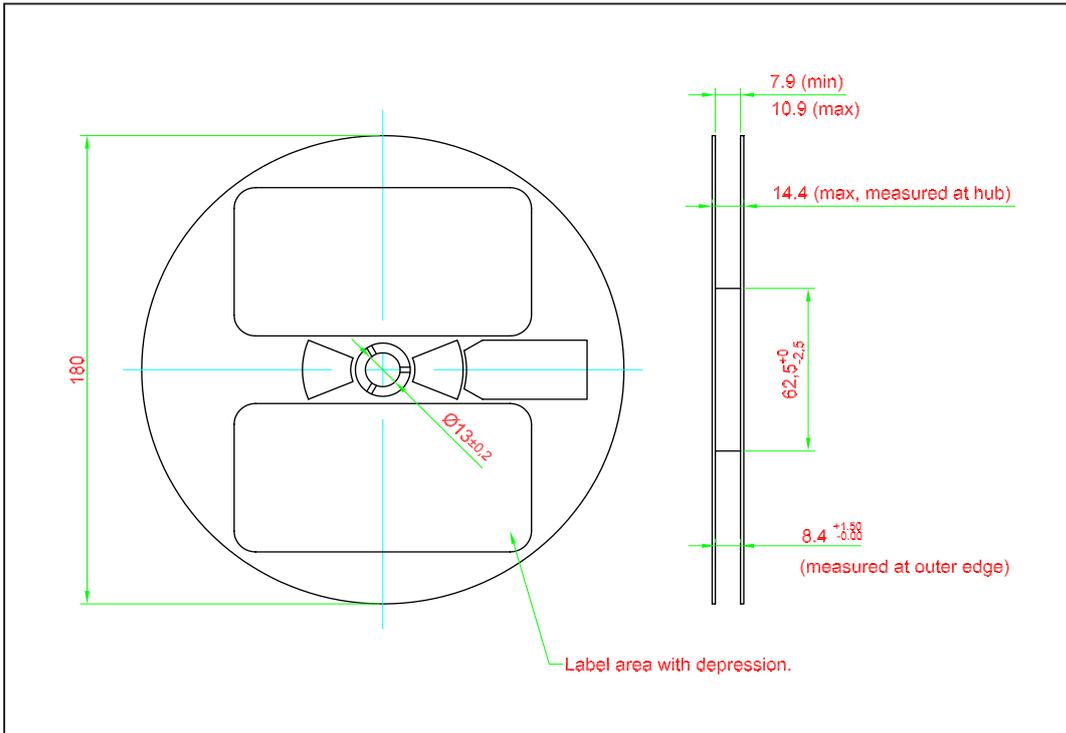
Recommended Solder Pad *Appx. 5.1*



Taping and orientation *Appx. 5.1*



Packaging Specification

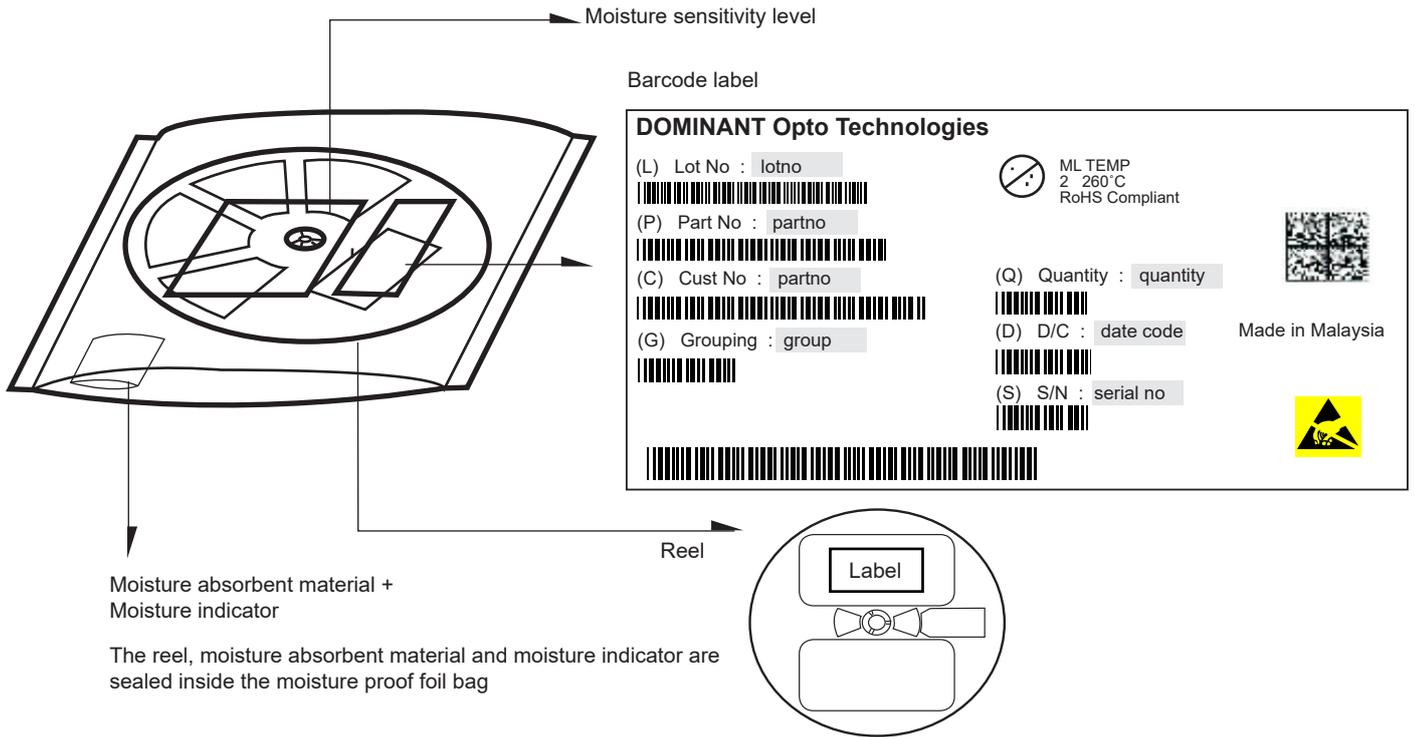


	Reel Diameter (mm)	Quantity (pcs)	*Ordering Number
Standard Packing	180	3000	DNZB-DJG-xxx-x-x
Optional Packing	329	10000	DNZB-DJG-xxx-x-x-J

Notes:

* For ordering purpose only. Please consult sales and marketing for details.

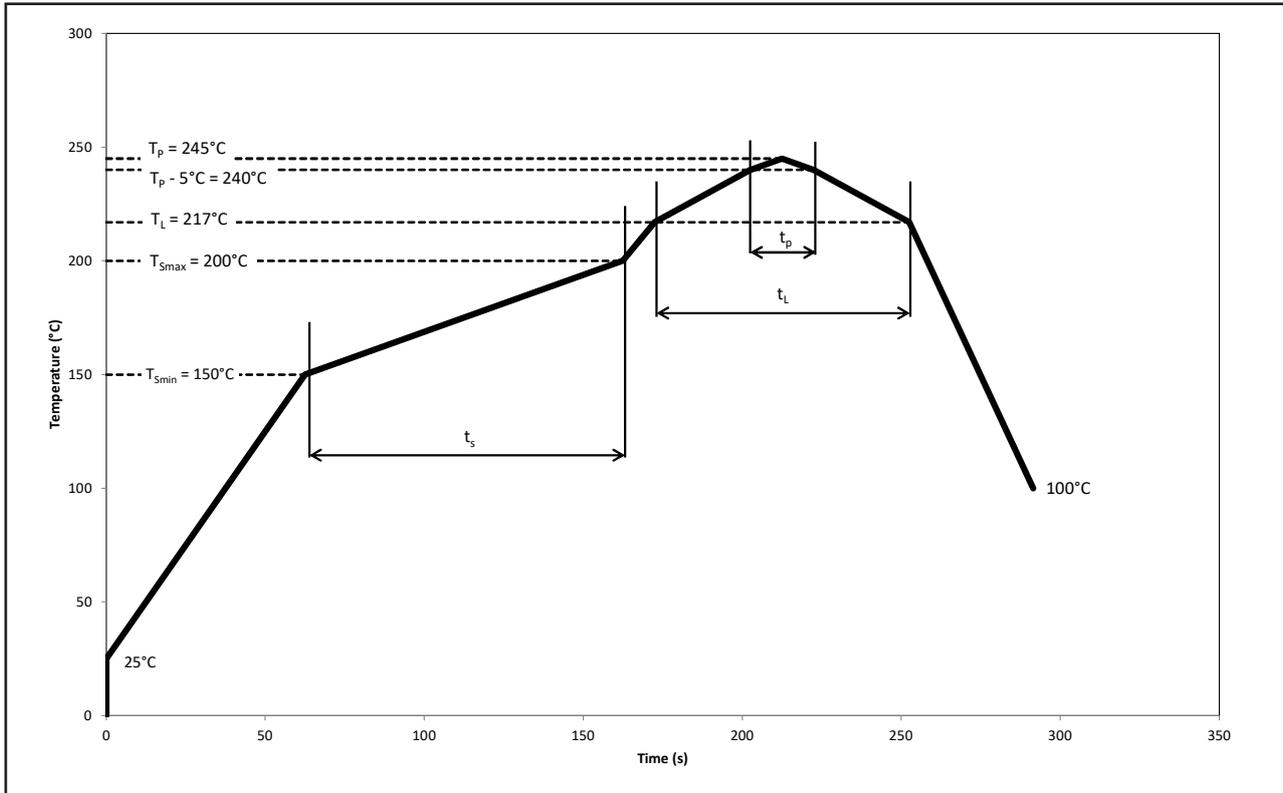
Packaging Specification



Quantity per bag (pcs)	Average 1pc Mini DomiLED (g)	1 completed bag (g)
3000	0.007	200 ± 10
10000	0.007	550 ± 10

Recommended Pb-free Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free Assembly			Unit
		Min.	Recommended	Max.	
Ramp-up rate to preheat 25°C to T_{smin}	-	-	2	3	°C/s
Time t_s T_{smin} to T_{smax}	t_s	60	100	120	s
Ramp-up rate to peak T_L to T_p	-	-	2	3	°C/s
Liquidous temperature	T_L	-	217	-	°C
Time above liquidous temperature	t_L	60	80	150	s
Peak temperature	T_p	-	245	260	°C
Time within 5°C of the specified peak temperature $T_p - 5°C$	t_p	10	20	30	s
Ramp-down rate T_p to 100°C	-	-	3	6	°C/s
Time 25°C to T_p	-	-	-	480	s

Appendix

1) **Brightness:**

- 1.1 Luminous intensity is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).
- 1.2 Luminous flux is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).
- 1.3 Radiant intensity is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).
- 1.4 Radiant flux is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).

2) **Color:**

- 2.1 Chromaticity coordinate groups are measured at current pulse 25 ms(typ) with an internal reproducibility of ± 0.005 and an expanded uncertainty of ± 0.01 (accordingly to GUM with a coverage factor of $k=3$).
- 2.2 Dominant wavelength is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 0.5\text{nm}$ and an expanded uncertainty of $\pm 1\text{nm}$ (accordingly to GUM with a coverage factor of $k=3$).

3) **Voltage:**

- 3.1 Forward Voltage, V_f is measured when a current pulse of 8 ms(typ) with an internal reproducibility of $\pm 0.05\text{V}$ and an expanded uncertainty of $\pm 0.1\text{V}$ (accordingly to GUM with a coverage factor of $k=3$).

4) **Typical Values:**

- 4.1 Due to the specific conditions of semiconductor devices' manufacturing processes, the provided typical data and calculated correlations of technical parameters should only be considered as statistical values. It is important to note that the actual parameters of individual devices may deviate from these typical data, calculated correlations or the typical characteristic line. Dominant reserves the right to update this typical data without prior notice, particularly in response to technical enhancements.

5) **Tolerance of Measure**

- 5.1 Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimension are specific in mm.

6) **Reverse Voltage:**

- 6.1 Not designed for reverse operation. Continuous reverse voltage can cause migration and LED damage.

Revision History

Page	Subjects	Date of Modification
-	Initial Release	14 Apr 2014
7	Add graph: Allowable Forward Current Vs Duty Ratio	11 Nov 2014
1, 3, 8, 12	Add Features Add Characteristics Add Notes in Packaging Outline Update Packaging Specification	12 Oct 2015
4, 5	Update Color Bin Structure	28 Apr 2016
1, 10, 14	Add Features Error on Taping and Orientation Add Appendix	06 Apr 2017
1, 2, 5, 6, 7, 11, 12, 13	Update Features: AEC-Q101 to AEC-Q102 Update Test Condition for Peak Pulse Current Update Operating & Storage Temperature Add Thermal Resistance Add Vf Binning (Optional) Update Graph Add Bigger Reel Option Update Recommended Pb-free Soldering Profile	06 Aug 2025

NOTE

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Dispose of product is in accordance with local, regional, national and international regulations.

About Us

DOMINANT Opto Technologies is a dynamic company that is amongst the world's leading automotive LED manufacturers. With an extensive industry experience and relentless pursuit of innovation, DOMINANT's state-of-art manufacturing and development capabilities have become a trusted and reliable brand across the globe. More information about DOMINANT Opto Technologies, a ISO/TS 16949 and ISO 14001 certified company, can be found under <http://www.dominant-semi.com>.

Please contact us for more information:

DOMINANT Opto Technologies Sdn. Bhd.
Lot 6, Batu Berendam, FTZ Phase III, 75350 Melaka, Malaysia
Tel: (606) 283 3566 Fax: (606) 283 0566
E-mail: sales@dominant-semi.com
